

## R-C Thermal Model Parameters

### DESCRIPTION

The parametric values in the R-C thermal model have been derived using curve-fitting techniques. R-C values for the electrical circuit in the Foster/Tank and Cauer/Filter configurations are included. When implemented in P-Spice, these values have matching characteristic curves to the single-pulse transient thermal impedance curves for the MOSFET.

These RC values can be used in the P-SPICE simulation to evaluate the thermal behavior of the MOSFET junction temperature under a defined power profile. These techniques are described in Application Note AN609, "Thermal Simulation of Power MOSFETs on the P-Spice Platform."

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
<b>Thermal Resistance (°C/W)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RT1	15.6312	43.9707 m	N/A
RT2	40.8698	1.2169	N/A
RT3	21.7919	321.0293 m	N/A
RT4	6.7071	1.1181	N/A
<b>Thermal Capacitance (Joules/°C)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CT1	72.2258 m	24.4063 m	N/A
CT2	1.9882	1.2080 m	N/A
CT3	1.3539	2.1222	N/A
CT4	6.7570 m	12.5919 m	N/A

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION****R-C VALUES FOR FILTER CONFIGURATION**

Thermal Resistance ( $^{\circ}\text{C}/\text{W}$ )			
Junction to	Ambient	Case	Foot
RF1	7.1626	1.5045	N/A
RF2	14.4537	123.6809 m	N/A
RF3	15.8360	819.1907 m	N/A
RF4	47.5477	252.6284 m	N/A
Thermal Capacitance (Joules/ $^{\circ}\text{C}$ )			
Junction to	Ambient	Case	Foot
CF1	5.4167 m	1.0552 m	N/A
CF2	49.2744 m	14.4672 m	N/A
CF3	358.5101 m	2.9659 m	N/A
CF4	902.0871 m	3.5436	N/A

**Note**

NA indicates not applicable

